

Isc N-Channel MOSFET Transistor

AOTF2142L

• FEATURES

- With TO-220F package
- · Low input capacitance and gate charge
- · Low gate input resistance
- · Reduced switching and conduction losses
- Optimized for fast-switching applications
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

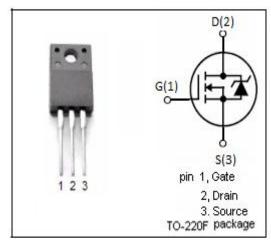
· Switching applications

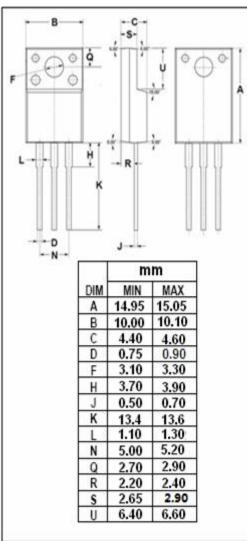


SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	40	V	
V _{GSS}	Gate-Source Voltage	±20	V	
I _D	Drain Current-Continuous @Tc=25°C Tc=100°C	112 78	А	
I _{DM}	Drain Current-Single Pulsed	800	Α	
P _D	Total Dissipation @Tc=25℃	41	W	
Tj	Max. Operating Junction Temperature	175	$^{\circ}$ C	
T _{stg}	Storage Temperature	-55~175	$^{\circ}$	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT		
Rth(ch-c)	Channel-to-case thermal resistance	3.6	°C/W		
Rth(ch-a)	Channel-to-ambient thermal resistance	60	°C/W		







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D =0.25mA	40			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = ±20V; I _D =0.25mA	1.3		2.3	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =20A		1.55	1.9	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} = 0V			±1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 40V; V _{GS} = 0V;Tj=25°C V _{DS} = 40V; V _{GS} = 0V; Tj=55°C			1 5	μА
V _{SDF}	Diode forward voltage	I _{SD} =1A, V _{GS} = 0 V			1.0	V

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